

isc N-Channel MOSFET Transistor

2SK3510-Z

FEATURES

• Drain Current : I_D= 83A@ T_C=25 ℃

- Drain Source Voltage
 - : V_{DSS}= 75V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 8.5 \text{m} \Omega \text{ (Max)} @ V_{GS} = 10 \text{V}$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

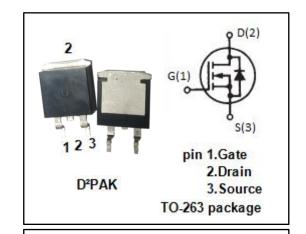
 motor drive, DC-DC converter, power switch and solenoid drive.

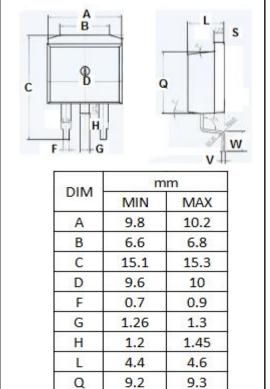
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	75	V
V _{GS}	Gate-Source Voltage-Continuous	±20	V
I _D	Drain Current-Continuous	83	Α
I _{DM}	Drain Current-Single Pluse	332	Α
P _D	Total Dissipation @T _C =25℃	125	W
TJ	Max. Operating Junction Temperature -55~150		$^{\circ}$ C
T _{stg}	Storage Temperature	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1	°C/W





1.25

0.4

2.6

1.35

0.6

2.8

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S

W



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	75		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1mA	2	4	V
R _{DS(on)}	Drain-Source On-Resistance	VGS= 10V; ID= 42A		8.5	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =75V; V _{GS} = 0		10	uA
V _{SD}	Forward On-Voltage	I _S = 83A; V _{GS} = 0		1	V



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